



Solid State Devices, Inc.

14830 Valley View Blvd * La Mirada, Ca 90638

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Designer's Data Sheet

FEATURES:

- Low-Level Gate Characteristics
- $I_{GT} = 200 \mu A$ (Max) @ 25°C
- Low Holding Current $I_H = 1 mA$ (Max) @ 25°C
- Anode Common to Case
- Hermetically Sealed
- TX, TXV, S-Level Screening Available. Consult Factory

SFS2510 thru SFS2540

25 AMPS
100 – 400 VOLTS
FAST SWITCHING
SILICON CONTROLLED
RECTIFIER



TO-48

MAXIMUM RATINGS (T _J = 25°C UNLESS OTHERWISE NOTED, R _{GK} = 1K Ω)		Symbol	Value	Units
Peak Repetitive Reverse Voltage and DC Blocking Voltage	SFS2510	V _{DRM}	100	Volts
	SFS2520		200	
	SFS2525	250		
	SFS2530	V _{RRM}	300	
	SFS2540		400	
Non-Repetitive Peak Reverse Blocking Voltage (t ≤ 5.0 ms)	SFS2510	V _{RSM}	150	Volts
	SFS2520		300	
	SFS2525		350	
	SFS2530		400	
	SFS2540		500	
RMS On-State Current (All Conduction Angles)		I _{T (RMS)}	35	Amps
Average On-State Current	T _C = 50°C	I _{T (AV)}	25	Amps
Peak Non-Repetitive Surge Current (One Cycle, 60 Hz, T _J = 120°C, t = 8.3 ms)		I _{TSM}	210	Amps
Peak Gate Power		P _{GM}	60	Watts
Average Gate Power		P _{G (AV)}	1.0	Watts
Peak Gate Current		I _{GM}	10	Amps
Peak Gate Voltage		V _{GM}	15	Volts
Operating Junction Temperature Range		T _J	-65 to +135	°C
Storage Temperature Range		T _{stg}	-65 to +150	°C
Thermal Resistance, Junction to Case		R _{θJC}	1.45	°C/W



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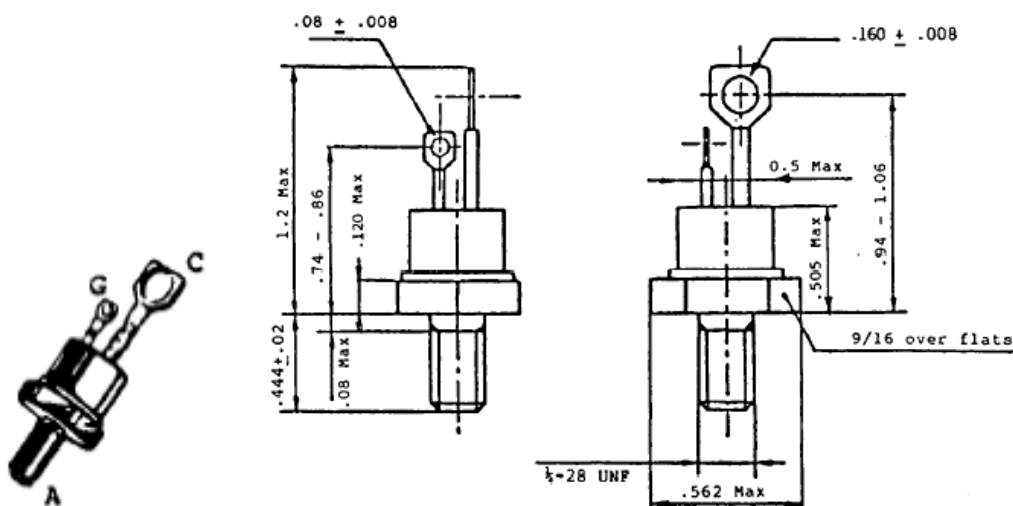
SFS2510 thru SFS2540

ELECTRICAL CHARACTERISTICS	Symbol	Min	Max	Unit
Peak Reverse Blocking Current (Rated V_{RRM} , $T_C = 25^\circ\text{C}$)	I_{RRM}	—	2	mA
Peak Forward Blocking Current (Rated V_{DRM} , $T_C = 25^\circ\text{C}$)	I_{DRM}	—	2	mA
Peak On-State Voltage ($I_F = 25\text{ A Peak}$, $t = 1\text{ ms}$, Duty Cycle $\leq 1\%$) ($I_F = 100\text{ A Peak}$, $t = 1\text{ ms}$, Duty Cycle $\leq 1\%$)	V_{TM}	— —	2.05 2.25	Volts
Gate Trigger Current ($V_D = 12\text{ V}_{DC}$, $R_L = 33\ \Omega$)	I_{GT}	—	180	mA
Gate Trigger Voltage ($V_D = 12\text{ V}_{DC}$, $R_L = 33\ \Omega$)	V_{GT}	—	1.5	Volts
Holding Current ($I_T = 500\text{ mA}$, Gate Open)	I_H	—	70	mA

NOTES:

1/ Unless Otherwise Specified, All Electrical Characteristics @ $T_C = 25^\circ\text{C}$, $R_{GK} = 1\text{K}\ \Omega$.

PACKAGE OUTLINE: TO-48



Available Part Numbers:

SFS2510	SFS2520	SFS2525	SFS2530	SFS2540
SFS2510/48	SFS2520/48	SFS2525/48	SFS2530/48	SFS2540/48

PIN ASSIGNMENT (Standard)

Package	Cathode	Gate	Anode
TO-48 (/48)	Terminal 1	Terminal 2	Cathode

NOTE: All specifications are subject to change without notification.
SCD's for these devices should be reviewed by SSDI prior to release.

F3N0H

DATA SHEET #: SCR006A

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